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March 2009

FDG410NZ Single N-Channel PowerTrench[®] MOSFET 20 V, 2.2 A, 70 m Ω

Features

- Max $r_{DS(on)}$ = 70 m Ω at V_{GS} = 4.5 V, I_D = 2.2 A
- Max $r_{DS(on)}$ = 77 m Ω at V_{GS} = 2.5 V, I_D = 2.0 A
- Max r_{DS(on)} = 87 mΩ at V_{GS} = 1.8 V, I_D = 1.8 A
- Max $r_{DS(on)}$ = 115 m Ω at V_{GS} = 1.5 V, I_D = 1.5 A
- HBM ESD protection level > 2 kV (Note 3)
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability
- Fast switching speed
- Low gate charge
- RoHS Compliant



General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized use in small switching regulaters, providing an extremely low $r_{DS(on)}$ and gate charge (Q_{σ}) in a small package.

6 D

5 | D

4 |S

Applications

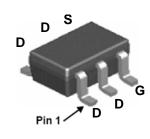
- DC/DC converter
- Power management

D 1

D 2

G 3

Load switch



SC70-6



Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			20	V	
V _{GS}	Gate to Source Voltage			±8	V	
1	-Continuous	T _A = 25 °C	(Note 1a)	2.2	Α	
D	-Pulsed	-Pulsed 6.				
D	Power Dissipation	T _A = 25 °C	(Note 1a)	0.42	W	
P _D	Power Dissipation	(Note 1b)	0.38	VV		
T _J , T _{STG}	Operating and Storage Junction Tempe	erature Range		-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	300	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	(Note 1b)	333	°C/vv

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Reel Size Tape Width	
.41	FDG410NZ	SC70-6	7 "	8 mm	3000 units

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, \ V_{GS} = 0 \ V$	20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		17		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 16 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±10	μΑ
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	0.4	0.7	1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-3		mV/°C
	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 2.2 \text{ A}$		50	70	mΩ
		V _{GS} = 2.5 V, I _D = 2.0 A		56	77	
rac)		V _{GS} = 1.8 V, I _D = 1.8 A		67	87	
r _{DS(on)}		V _{GS} = 1.5 V, I _D = 1.5 A		83	115	1115.2
		$V_{GS} = 4.5 \text{ V}, I_D = 2.2 \text{ A},$ $T_J = 125 \text{ °C}$		71	100	
9 _{FS}	Forward Transconductance	$V_{DD} = 5 \text{ V}, \ \text{I}_{D} = 2.2 \text{ A}$		11		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			400	535	pF
C _{oss}	Output Capacitance	── V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		70	95	pF
C _{rss}	Reverse Transfer Capacitance			45	70	pF
R _g	Gate Resistance			2.8		Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			5.3	11	ns
t _r	Rise Time	V _{DD} = 10 V, I _D = 2.2 A,		2.3	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		18	33	ns

t _r	Rise Time	$V_{DD} = 10 V, I_D = 2.2 A,$	2.3	10	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 4.5 V, R_{GEN} = 6 Ω	18	33	ns
t _f	Fall Time		2.3	10	ns
Qg	Total Gate Charge		5.1	7.2	nC
Q _{gs}	Gate to Source Charge	V _{GS} = 4.5 V, V _{DD} = 10 V, I _D = 2.2 A	0.6		nC
Q _{gd}	Gate to Drain "Miller" Charge	0-2.27	1.0		nC

Drain-Source Diode Characteristics

I _S	Maximum Continuous Drain-Source Diode Forward Current				0.35	A
V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = 0.35 A (Note 2)		0.6	1.2	V
t _{rr}	Reverse Recovery Time	I _F = 2.2 A, di/dt = 100 A/μs		11	20	ns
Q _{rr}	Reverse Recovery Charge			2.5	10	nC

Notes:

1. R_{0JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0JA} is determined by the user's board design.



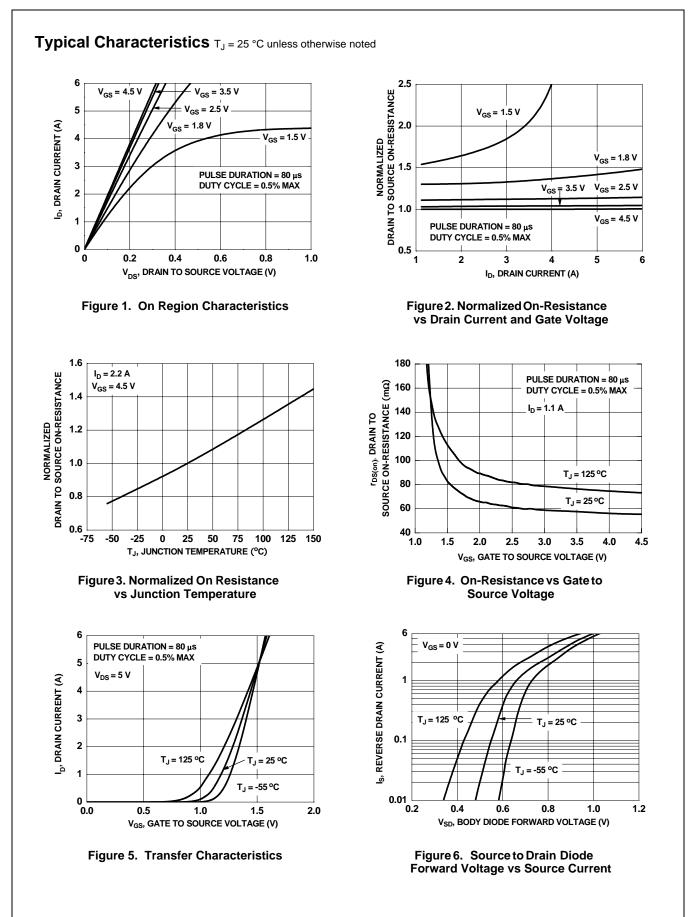
a. 300 °C/W when mounted on a 1 in² pad of 2 oz copper.

b. 333 °C/W when mounted on a minimum pad of 2 oz copper.

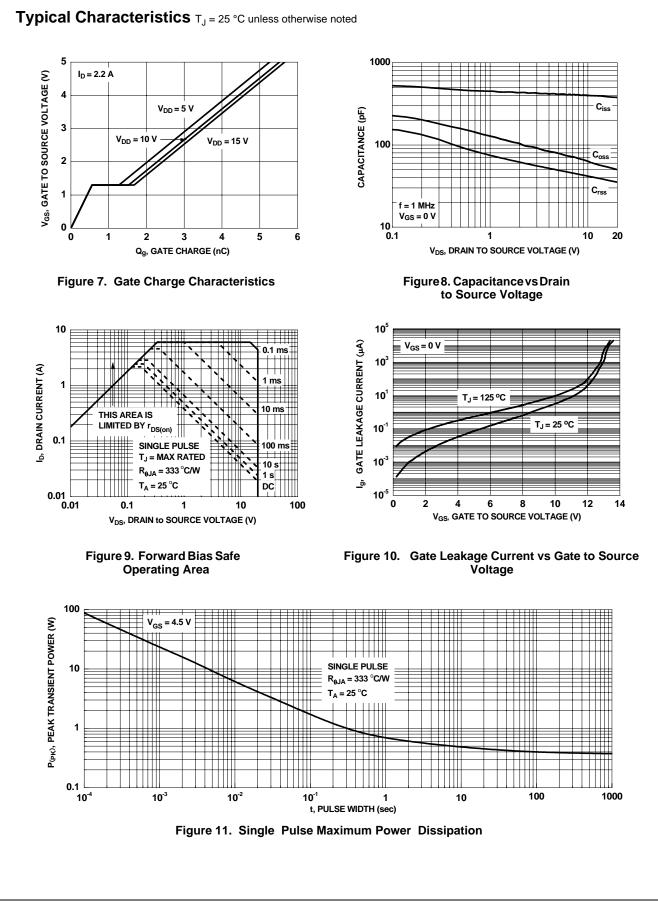


Pulse Test: Pulse Width < 300 μs, Duty cycle < 2.0%.
The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

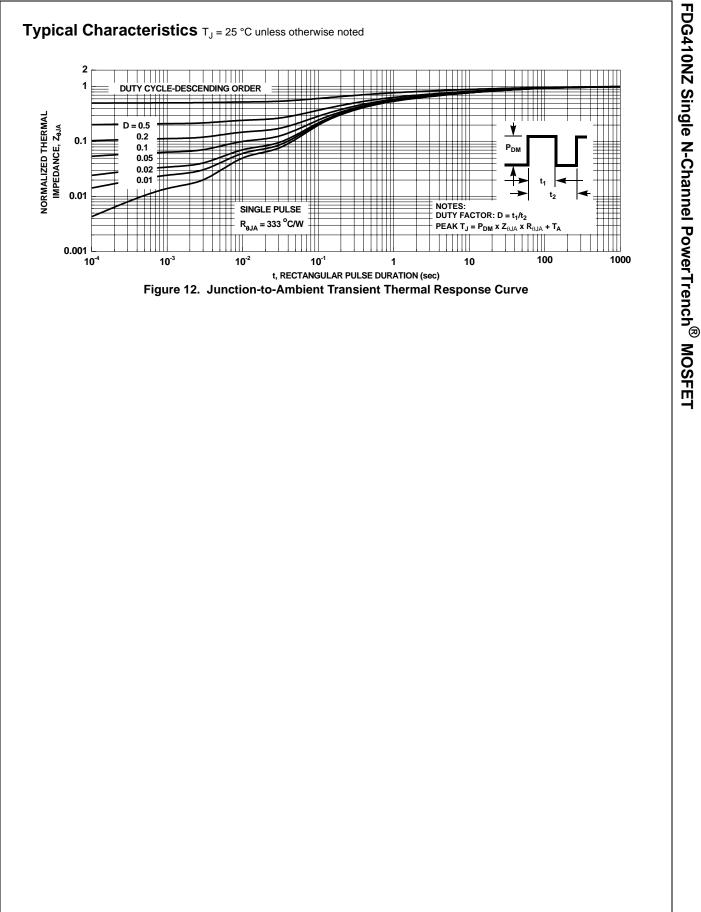
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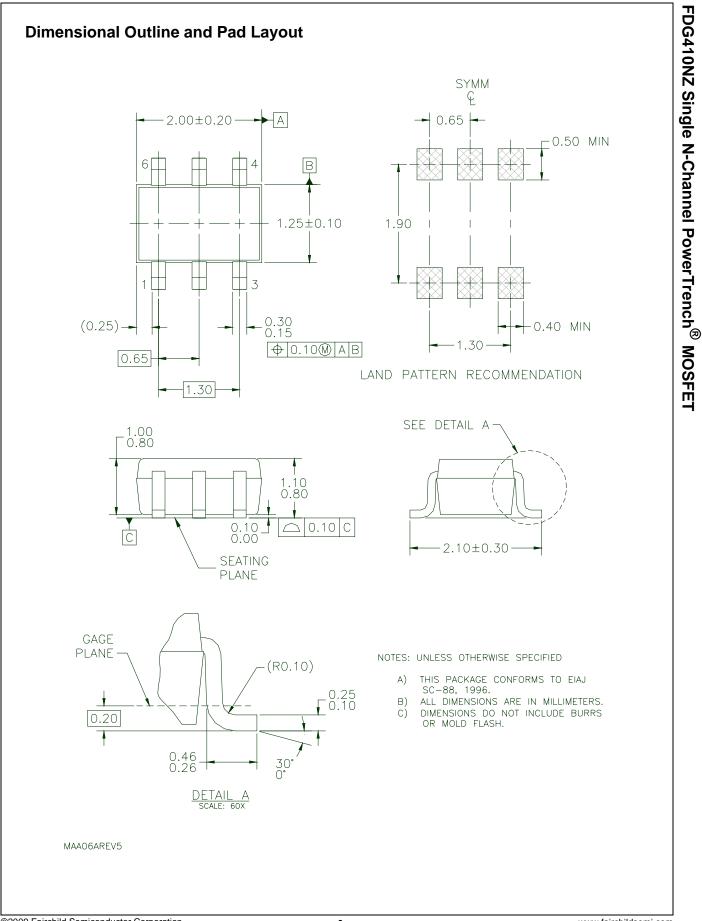


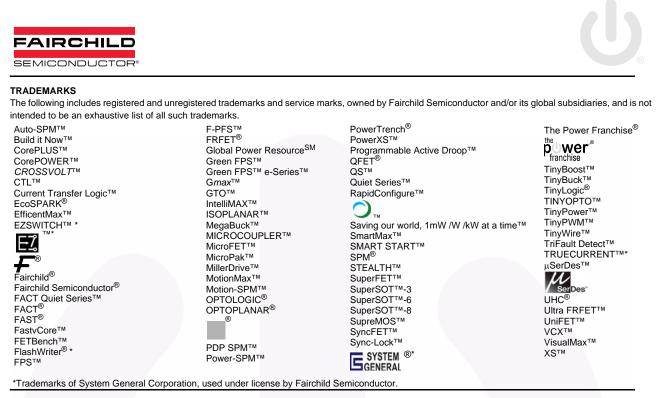
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